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# LF353

## **Dual Operational Amplifier (JFET)**

#### **Features**

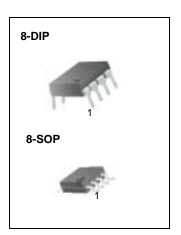
• Internally trimmed offset voltage: 10mV

Low input bias current: 50pA
Wide gain bandwidth: 4MHz
High slew rate: 13V/μs

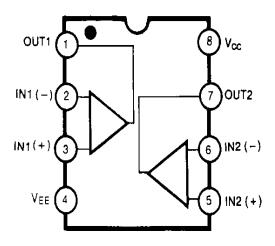
• High Input impedance:  $10^{12}\Omega$ 

#### **Description**

The LF353 is a JFET input operational amplifier with an internally compensated input offset voltage. The JFET input device provides wide bandwidth, low input bias currents and offset currents.

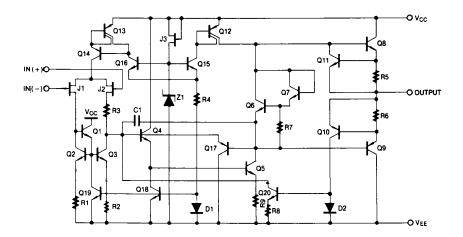


### **Internal Block Diagram**



### **Schematic Diagram**

(One Section Only)



### **Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit	
Power Supply Voltage	Vcc	±18	V	
Differential Input Voltage	VI(DIFF)	30	V	
Input Voltage Range	Vı	±15	V	
Output Short Circuit Duration	-	Continuous	-	
Power Dissipation	PD	500	mW	
Operating Temperature Range	Topr	0 ~ +70	°C	
Storage Temperature Range	TSTG	-65 ~ +150	°C	

### **Electrical Characteristics**

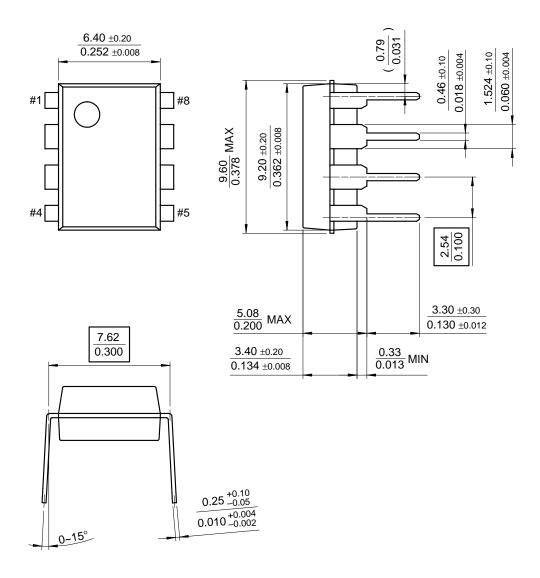
(VCC =+15V, VEE= -15V, TA=25  $^{\circ}$ C, unless otherwise specified)

Parameter	Symbol	Co	nditions	Min.	Тур.	Max.	Unit
Input Offset Voltage	Vio	R <sub>S</sub> =10KΩ		-	5.0	10	mV
			0 °C≤TA≤+70 °C	-	-	-	-
Input Offset Voltage Drift	ΔV10/ΔΤ	Rs=10KΩ	0 °C≤T <sub>A</sub> ≤+70 °C	-	10	-	μV/°C
Input Offset Current	lio			-	25	100	рА
			0 °C≤T <sub>A</sub> ≤+70 °C	-	-	4	nA
Input Bias Current	Inivo	·		-	50	200	рА
	IBIAS		0 °C≤T <sub>A</sub> ≤+70 °C	-	-	8	nA
Input Resistance	Rı	-		-	10 <sup>12</sup>	-	Ω
Large Signal Voltage Gain	Gv	$VO(P-P) = \pm 10V$		25	100	-	V/mV
		$R_L = 2K\Omega$	0 °C≤T <sub>A</sub> ≤+70 °C	15	-	-	-
Output Voltage Swing	VO(P_P)	RL = 10KΩ		±12	±13.5	-	V
Input Voltage Range	VI(R)	-		±11	±15/-12	-	V
Common Mode Rejection Ratio	CMRR	Rs≤10KΩ		70	100	-	dB
Power Supply Rejection Ratio	PSRR	Rs≤10KΩ		70	100	-	dB
Power Supply Current	Icc	-		-	3.6	6.5	mA
Slew Rate	SR	G <sub>V</sub> = 1		-	13	-	V/μS
Gain-Bandwidth Product	GBW	-		-	4	-	MHz
Channel Seperation	CS	f = 1Hz ~ 20KHz (Input referenced)		-	120	-	dB
Equivalent Input Noise Voltage	VNI	$R_S = 100\Omega$ f = 1KHz		-	16	-	nV/ √Hz
Equivalent Input Noise Current	INI	f = 1KHz		-	0.01	-	pA/ √Hz

### **Mechanical Dimensions**

#### **Package**

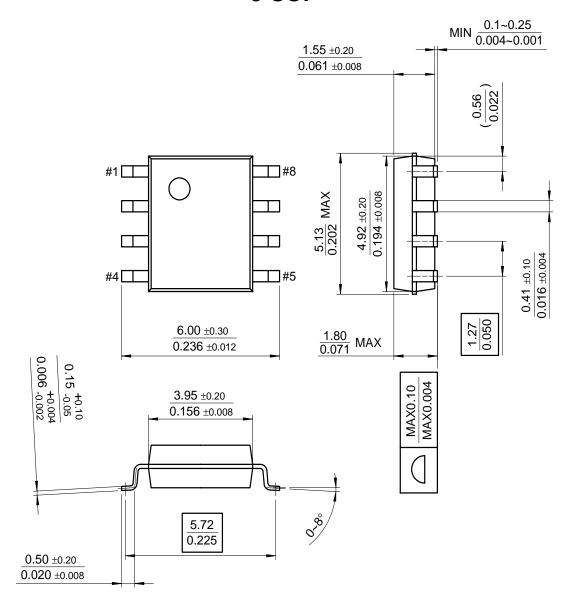
## 8-DIP



#### **Mechanical Dimensions**

### Package

## 8-SOP



#### **Ordering Information**

Product Number	Package	Operating Temperature
LF353N	8-DIP	0 ~ + 70°C
LF353M	8-SOP	0~+70 C

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